Hallogic Hall-Effect Sensor Assembly



OHB900

Features:

- Non-contact motion sensing
- Operates over a broad range of supply voltages (4.5 V to 25 V)
- Excellent temperature stability
- Hall element, linear amplifier and Schmitt trigger on a single Hallogic silicon chip
- Performs in dirty environments over wide temperature range
- 0.125" (3.18 mm) wide gap



Description:

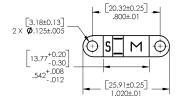
The OHB900 consists of a Hall-effect sensor similar to the OH180U and a rare earth magnet mounted in a low-cost plastic housing. The magnet produces optimum magnetic flux at the Hall-effect sensor location. The sensor has an open collector transistor output, which is activated when the slot is open. When the slot is blocked by a ferrous material that reduces the magnetic flux density at the Hall-effect sensor location, the open collector output transistor switches off. The device provides up to 25 mA of sink current. Output characteristics are constant at switching frequencies from DC to over 200 kHz.

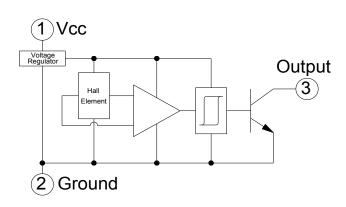
The Uni-Polar turns on with a (logic level "0") after a sufficient magnetic field from the south pole of a magnet approaches the symbolized face of the device (Operating Point) and turns off (logic level "1") after the magnetic field reached a minimum value. This feature makes these sensors ideal for applications in non-contact switching operations.

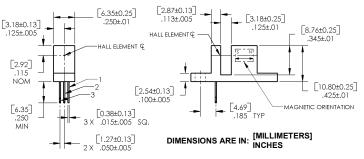
Applications:

- Non-contact slotted magnetic switch
- Harsh environment encoder
- · Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information				
Part Number	Description			
ОНВ900	Slotted Switch			







Pin#	Description			
1	Vcc			
2	Ground			
3	Output			



RoHS

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Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

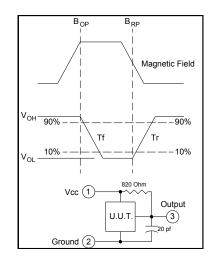
Supply Voltage, V _{CC}	25 V
Storage Temperature Range, T _S	-50°C to +160° C
Operating Temperature Range, T _A	-40°C to +150° C
Lead Soldering Temperature (1/8 in. (3.2 mm) from case for 5 sec. with soldering iron)	260° C
Output ON Current, I _{SINK}	25 mA
Output OFF Voltage, V _{OUT}	25 V
Magnetic Flux Density, B	Unlimited

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
I _{CC}	Supply Current	-	4	7	mA	V _{CC} = 24 V, Output Off
V_{OL}	Output Saturation Voltage	-	100	400	mV	V_{CC} = 4.5 V, I_{OL} = 20 mA, Slot Open
I _{OH}	Output Leakage Current	-	0.1	10	μA	V = 4.5 V, V _{OUT} = 24 V, Slot Blocked
t _r	Output Rise Time	-	0.21	1	μs	$R_L = 820 \Omega, C_L = 20 pF$
t _f	Output Fall Time	-	0.1	1	μs	$R_L = 820 \Omega, C_L = 20 pF$

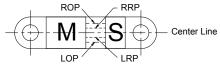
Notes:

- (1) Slot blocked with a ferrous material to interrupt magnetic flux.
- (2) See Hall-effect data sheet OH090 through OHS3100 Series for additional information for reference only.



	Right	Right	Left	Left
	Operate	Release	Release	Operate
	Point	Point	Point	Point
Minimum	0.073"	0.045"	-0.045"	-0.073"
	[1,85mm]	[1,14mm]	[-1,14mm]	[-1,85mm]
Maximum	0.003"	-0.005"	0.005"	-0.003"
	[0,08mm]	[-0.127mm]	[0.127mm]	[-0,08mm]

Measurements are referenced to Center Line.

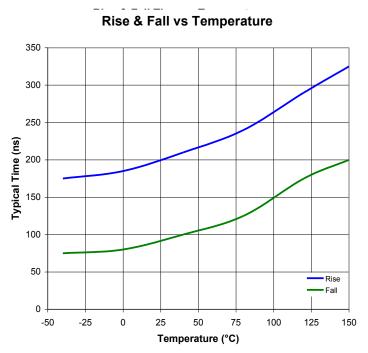


Vane - Material = 1018 Cold Rolled Steel - 0.03" [0.76mm] Thick Location = 0.50" [12.7mm] from Bottom of Slot

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Performance



Icc vs Temperature 9 Icc ON Icc OFF 8 7 6 Typical Icc (mA) 2 25 50 -25 0 75 100 125 -50 150 Temperature (°C)

Saturation Voltage vs Temperature

